# RICOH

### 30V Input 2A Buck DC/DC Converter

NO.EA-206-111123

### OUTLINE

The R1243x Series is the CMOS-based Step-Down DC/DC Converter with internal Nch high side Tr. (0.175Ω), which can provide the maximum 2A output current. The IC consists of an Oscillator, a PWM control circuit, a Reference Voltage unit, an Error amplifier, phase compensation circuits, a slope circuit, a soft start circuit, protection circuits, internal voltage regulators, and a switch for bootstrap circuit. The R1243x Series can make up a Step-Down DC/DC Converter with the following external components: an inductor, resistors, a diode, and capacitors.

The R1243x series are current mode operating type DC/DC converter which does not require external current sense resistor, and it works high speed response time, high efficiency and compatible with ceramic capacitors.

There are two types for the oscillator frequency. A/B version's frequency is fixed 1000kHz, and C/D version's frequency is fixed 330kHz.As a protection function, it has cycle by cycle peak current limit function, short protection function, thermal shutdown function and UVLO.

There are two types for short protection, A/C version has latch protection function with 2ms delay time, and B/D version has fold back protection function that keep operating at short condition with lower operating frequency and limiting the Lx current.

The R1243 Series has the built-in soft start time (Typ. 0.4ms). In addition to this, the soft start time is adjustable by adding an external capacitor. The R1243x Series has the FLG pin, which mainly monitors the FB pin voltage and gives the flag output by the Nch open drain if the abnormal condition is detected.

Since the packages for these ICs are HSOP-8E, and DFN(PLP)2527-10, therefore high density mounting of the ICs on boards is possible.

### FEATURES

Operating Voltage	4.5V ~ 30V
Standby Function	. Τγρ. 0μΑ, Max. 10μΑ (V <sub>IN</sub> =30V, CE="L")
Supply Current	. Typ. 0.7mA (VIN=30V VFB=1.0V)
Output Voltage Range	. 0.8V ~ 18V (Adjustable with external resistor)
Feed Back Voltage	. 0.5V with 1.4% accuracy
Output Current	. Max. 2A
Peak Current Limit Function	. Typ. 3.8A
Internal Nch MOSFET Driver	. Typ. 175mΩ
Maximum Duty Cycle	. Min. 85%
Operating Frequency	. Ver.A/B 1000kHz, Ver.C/D 330kHz
• Short protection delay time for Output Latch	. Typ. 2ms : Ver.A/C
• Built-in Foldback Protection and its Frequency	. 1/4 frequency at fold condition : Ver.B/D
	. Ver.B 250kHz, Ver.D 82.5kHz
Internal Soft Start Time	. Typ. 0.4ms, with TSS pin open
External Soft Start Time	. Typ. 12ms, with Css=0.1μF
Flag Output Function	. Typ. 0.25ms, FLG "OFF" delay time
UVLO Released Voltage	. Typ. 4.0V
Thermal Shutdown Function	. Typ. 160°C, with 35°C hysteresis
• Package	. HSOP-8E, DFN(PLP)2527-10
*)This is an approximate	e value, because output current depends on conditions and external parts.

### **APPLICATIONS**

- Power source for digital home appliance
- Power source for hand-held communication equipment, cameras, video instruments such as VCRs, camcorders.
- Power source for battery-powered equipment.
- Battery Charger

### **BLOCK DIAGRAMS**



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Ver.	fosc	Short Protection
А	1000kHz	Latch
В	1000kHz	Foldback
С	330kHz	Latch
D	330kHz	Foldback

### **PIN CONFIGURATIONS**



### **PIN DESCRIPTIONS**

### • HSOP-8E

Pin No	Symbol	Pin Description
1	BST	Bootstrap Pin
2	VIN	Power Supply Pin
3	Lx	Lx Switching Pin
4	GND	Ground Pin
5	FB	Feedback Pin
6	FLG	Flag Output Pin
7	CE	Chip Enable Pin (Active with "H")
8	TSS	Soft Start Pin

\* Tab is GND level. (They are connected to the reverse side of this IC.)

### • DFN(PLP)2527-10

Pin No	Symbol	Pin Description
1	Lx	Lx Switching Pin
2	Lx	Lx Switching Pin
3	GND	Ground Pin
4	FB	Feedback Pin
5	FLG	Flag Output Pin
6	CE	Chip Enable Pin (Active with "H")
7	TSS	Soft Start Pin
8	BST	Bootstrap Pin
9	VIN	Power Supply Pin
10	VIN	Power Supply Pin
* Tab is GND level. (Th	ey are connected to th	e reverse side of this IC.)

### **SELECTION GUIDE**

In the R1243x Series, type of short protection (Latch or Foldback), frequency (1000kHz, or 330kHz), and package for the ICs can be selected at the user's request.

Product Name	Package	Pb Free	Halogen Free			
R1243S001*-E2-FE	HSOP-8E	1,000pcs	Yes	Yes		
R1243K001*-TR	DFN(PLP)2527-10	5,000pcs	Yes	Yes		
* : Latch or Foldback, freque	ency can be selected at	the user's request				
(A) Fixed frequency 1000	kHz, Latch protection					
(B) Fixed frequency 1000	(B) Fixed frequency 1000kHz, Foldback protection					
(C) Fixed frequency 330kHz, Latch protection						
(D) Fixed frequency 330k	Hz, Foldback protection	l				

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Item	Rating	Unit	
VIN	Input Voltage	-0.3V~32V		V
VBST	Boost Pin Voltage	VLX-0.3V~VLX+6	SV	V
VLX	Lx Pin Voltage	-0.3V~VIN+0.3	5	V
Vce	CE Pin Input Voltage	-0.3V~V <sub>IN</sub> +0.3	5	V
Vfb	VFB Pin Voltage	-0.3V~6V		V
$V_{FLG}$	FLG Pin Voltage	-0.3V~6V		V
VTSS	TSS Pin Voltage	-0.3V~6V		V
	Power Dissipation (HSOP-8E)*	2900 <sup>*</sup>		
PD	Power Dissipation (DEN(PLP)2527 10) *	Standard Land Pattern	910 <sup>*</sup>	mW
		High Wattage Land Pattern 1400 <sup>*</sup>		
Ta	Operating Temperature Range	-40~85		°C
Tstg	Storage Temperature Range	-55~125		°C

\*) For Power Dissipation, please refer to PACKAGE INFORMATION to be described.

### ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

## **ELECTRICAL CHARACTERISTICS**

-	(Otherwise notified in Conditions, Viii=12V,Ta					
Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
VIN	Operating Input Voltage		4.5		30	V
Istandby	Standby Current	VIN=30V, VCE=0V		0	10	μA
IN	V <sub>IN</sub> Consumption Current	VIN=30V, VFB=1.0V		0.7	1.0	mA
VUVLO1	UVLO Detector Threshold	Falling	3.6	3.8	4.0	V
VUVLO2	UVLO Released Voltage	Rising	3.8	4.0	4.2	V
VUVLOHYS	UVLO Hysteresis	VUVLO2-VUVLO1		0.2		V
Vfb	Feedback Voltage		0.493	0.500	0.507	V
$\Delta V_{FB}/\Delta T$	Feedback Voltage Temperature Coefficient	-40°C ≤ Ta ≤ 85°C		±100		ppm /⁰C
fosc	Oscillator Frequency (Ver.A,B)		900	1000	1100	kHz
1050	Oscillator Frequency (Ver.C,D)		290	330	370	kHz
<b>f</b> flb	Fold back Frequency (Ver.B,D)	V <sub>FB</sub> <0.35V, fosc ratio		25		%
Maxduty	Oscillator Maximum Duty Cycle	VIN=6V	85	90	95	%
ITSS	TSS Pin Current	V <sub>TSS</sub> =0V		4.0		μA
tsso	Soft Start Time	TSS=open	0.2	0.4	0.8	ms
tss1	Soft Start Time	Css=0.1µF	6	12	18	ms
toly	Delay Time For Latch Protection (Ver.A,C)	V <sub>IN</sub> =5.0V		2.0		ms
ILXHOFF	High side switch Leakage Current	VIN=30V, VCE=0V		0	10	μA
RLXH	High side switch ON Resistance	VBST-VLX=4.5V		175		mΩ
ILIMLXH	High side switch Limited Current	VBST-VLX=4.5V	2.8	3.8		А
VCEH	CE "H" Input Voltage	VIN=30V	1.4			V
VCEL	CE "L" Input Voltage	VIN=30V			0.4	V
Ісен	CE "H" Input Current	$V_{IN}$ =30 $V$ , $V_{CE}$ =30 $V$	-1.0	0	1.0	μA
ICEL	CE "L" Input Current	VIN=30V, VCE=0V	-1.0	0	1.0	μA
Ігвн	FB "H" Input Current	VFB=2.0V	-1.0	0	1.0	μA
FBL	FB "L" Input Current	VFB=0.0V	-1.0	0	1.0	μA
<b>t</b> tsd	Thermal Shutdown Detect Temperature	Hysteresis 35°C		160		°C
Vflgl	FLG "L" Voltage	IFLG=1mA			0.4	V
FLGOFF	FLG "OFF" Current	VFLG=5.5V		0.0	1.0	μA
<b>t</b> FLGOFF	FLG "OFF" Delay Time		0.05	0.25	0.60	ms
Vovd	Over Voltage Detect Voltage	Vfb	0.55	0.60	0.65	V
Vuvd	Under Voltage Detect Voltage	Vfb	0.35	0.40	0.45	V

### RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

## **Typical Applications and Notes Concerning External Parts**

**Typical Applications** 



R1243x001C/D, Vout=1.8V, tss=0.4ms setting.





R1243x001A/B, Vout=5.0V, tss=12ms setting, Flag function using.

R1243x001C/D, Vout=5.0V, tss=12ms setting, Flag function using.



FLG pin is open-drain output that is pulled to ground at the conditions below:·CE="L" (Shut down)·UVLO (Released voltage Typ.4.0V)·Thermal Shutdown·VFB Over Voltage Detection (Typ.0.6V)·VFB Under Voltage Detection (Typ.0.4V)·Active Latch function (Ver.A/C)

·Tss pin's Over Voltage Protection after the completion of soft start (Typ.3V)

When the R1243x starts up, without the conditions above, after soft-start time,  $V_{FB}$  under voltage detection (Typ. 0.4V) is released, then after the released delay time (Typ. 0.25ms) the output of FLG pin pulled to "H". However, if  $V_{OUT}$  is used as  $V_{FLGIN}$ , even if the soft start time hasn't finished, the output of FLG pin becomes "H" or same as  $V_{OUT}$  and released delay time disappears.

Therefore, if soft-start time is used for the circuit sequence, the difference of the operation depending on the  $V_{FLGIN}$  (connected to  $V_{OUT}$  directly or other voltage source) must be cared.

### **Notes Concerning to External Parts**

- External components have to be connected as close as possible to the IC and have to be wired as short as possible. Especially, the capacitor connected between V<sub>IN</sub> and GND pin must be wired the shortest. If the impedances of the power supply line and the GND line are high, the operation can be unstable due to the switching current, which fluctuates the power line of the inside the IC. The impedances of power supply line and GND line must be as low as possible. It is necessary to give careful consideration to the large current flowing into the power supply, GND, Lx, Vou⊤ and inductor when designing their wirings. The wiring of output voltage setting resistance (RuP) and the wiring of inductor must be separated from load wiring.
- The capacitors to be used in the R1243x Series must be low ESR ceramic capacitors. The C<sub>IN</sub> capacitor between V<sub>IN</sub> and GND should be equal or more than 10µF. Please pay attention to the bias-dependent properties and the temperature variability characteristics of the ceramic capacitors.
- The internal phase compensation of this IC is designed within the recommended values of inductor and C<sub>OUT</sub> ceramic capacitor. If the inductor value is small, the peak values of the switching current increase along with the load current. When the peak value of the switching current reaches to the current limit, the over current protection circuit may start to function.
- If the parasitic capacitor of the schottky diode is large, the operation may result in unstable because of the large switching current when the switch is turned on. Please use the schottky diode with 100pF or less when the reverse voltage is 10V.
- The output voltage (V<sub>OUT</sub>) can be calculated by this equation: V<sub>OUT</sub> = V<sub>FB</sub> × (R<sub>UP</sub>+R<sub>BOT</sub>) / R<sub>BOT</sub>. By changing R<sub>UP</sub> and R<sub>BOT</sub>, the output voltage (V<sub>OUT</sub>) is adjustable. If resistance values of R<sub>UP</sub> and R<sub>BOT</sub> are high, the impedance of the FB pins become high, and the IC becomes vulnerable to an influence of noise. R<sub>BOT</sub> is recommended to be between 1.0kΩ to 4.7kΩ. If the operation become unstable due to the high impedance, it is important to consider lowering the impedance.
- In the IC, ESD protection diode is connected between CE pin and V<sub>IN</sub> pin. If there is a possibility that the CE pin voltage becomes higher than the V<sub>IN</sub> pin voltage, it is recommended to insert a 10kΩ resistance or more in order to prevent the large current flowing from CE pin into V<sub>IN</sub> pin.
- Connect the reverse side of the IC pad to GND. To improve the radiation of heat of the multiple-layered board, it is effective to make the Via on the connection part of the reverse side of the IC pad to release the heat to multiple layers.
- The flag resistor (R<sub>FLG</sub>) is recommended to be between 10kΩ to 100kΩ. If the flag function is not used, FLG pin has to be left open or connected to GND.
- If the soft start time adjustment function is not used, TSS pin must be left open. In this case, soft start time is set as 0.4ms (Typ.).
- After the completion of the soft start, latch function (Ver.A/C) starts to function. The internal counter starts counting up when the overcurrent protection circuits runs the current limit detection. When the internal counter counts up to 2ms(Typ.), latch function turns off the output. The turned off output can be reset when CE pin is changed to "L", and also V<sub>IN</sub> pin voltage became less than 3.8V (Typ.), which is UVLO detecting voltage. If the output voltage becomes more than the setting voltage (FB pin voltage is 0.50V (Typ.) within the latch timer period, the counter restores the default. Therefore, the careful attention is required when the power-supply voltage's start-up is slow and the output voltage is not reached to the setting voltage within the latch timer period after the completion of the soft start.
- After the completion of the soft start, fold back function (Ver.B/D) starts to function. The fold back function limits the oscillation frequencies into 1/4 when FB pin voltage becomes less than 0.35V (Typ.). Therefore, the careful attention is required when the power-supply voltage's start-up is slow and the output voltage

is not reached to the 70% (Typ.) of the setting voltage even for a short period of time after the completion of the soft start.

- The quality of the power supply circuit using the R1243x Series largely depends on the external components. The careful attention is required for the external component parameters.
- The careful attention is required for the maximum ratings (voltage, current, and wattage) of the external components, board layout pattern and the IC.
- The table on the next page shows the recommended values for setting output voltage.

### Table1 R1243 Recommended value for each Output Voltage

### · R1243x001A/B 1000kHz

Vin	Vout	L[μH]	Cουτ[μF]	$C_{SPD}^{*1}$	CBST[µF]	R <sub>BOT</sub> [kΩ]
$4.5 \le V_{IN} \le Max$	0.8 ≤ V <sub>OUT</sub> ≤ 1.2	2.2	47	*1	0.47	2.0
$4.5 \le V_{IN} \le Max$	1.2 ≤ Vout ≤ 1.8	2.2	22	*1	0.47	2.0
$4.5 \le V_{IN} \le Max$	1.8 ≤ Vouт ≤ 2.5	4.7	10	*1	0.47	2.0
$4.5 \le V_{IN} \le 6$	2.5 ≤ Vou⊤ ≤ Maxduty	4.7	22	open	0.47	2.0
$6 \leq V_{IN} \leq Max$	2.5 ≤ Vout ≤ 5	4.7	10	*1	0.47	2.0
Min ≤ V <sub>IN</sub> ≤ Max	5 ≤ Vouт ≤ Maxduty	4.7	10	*1	0.47	2.0

### · R1243x001C/D 330kHz

VIN	Vout	L[µH]	Cουτ[μF]	$C_{SPD}^{*2}$	CBST[µF]	$R_{BOT}[k\Omega]$
$4.5 \le V_{IN} \le 7.5$	0.8 ≤ Vout ≤ 1.2	4.7	47×2	open	0.47	2.0
$4.5 \le V_{IN} \le 7.5$	1.2 ≤ Vouт ≤ Maxduty	10	47×2	open	0.47	2.0
7.5 ≤ V <sub>IN</sub> ≤ Max	0.8 ≤ Vout ≤ 1.2	4.7	47×2	*2	0.47	2.0
7.5 ≤ V <sub>IN</sub> ≤ 12	1.2 ≤ Vout ≤ 2.5	10	47	*2	0.47	2.0
$7.5 \le V_{IN} \le Max$	1.2 ≤ Vouт ≤ 2.5	4.7	47	*2	0.47	2.0
7.5 ≤ V <sub>IN</sub> ≤ Max	2.5 ≤ Vout ≤ 5	10	22	*2	0.47	2.0
7.5 ≤ V <sub>IN</sub> ≤ Max	5 ≤ Vouт ≤ 18	10	10×2	*2	0.47	2.0

### \*1 R1243x001A/B 1000kHz CSPD

Vout[V]	CSPD[pF]	Rup[kΩ]	<b>R</b> βοτ <b>[kΩ]</b>
0.8	1800	1.2	2.0
1	1200	2.0	2.0
1.2	1000	2.8	2.0
1.5	820	4.0	2.0
1.8	560	5.2	2.0
2.5	390	8.0	2.0
3.3	220	11.2	2.0
5	150	18.0	2.0
6	120	22.0	2.0
9	82	34.0	2.0
12	56	46.0	2.0
15	47	58.0	2.0
18	47	70.0	2.0

### \*2 R1243x001C/D 330kHz CSPD

Vout[V]	CSPD[pF]	Rup[kΩ]	<b>R</b> βΟΤ <b>[kΩ]</b>
0.8	2700	1.2	2.0
1	2200	2.0	2.0
1.2	1500	2.8	2.0
1.5	1200	4.0	2.0
1.8	1000	5.2	2.0
2.5	560	8.0	2.0
3.3	390	11.2	2.0
5	220	18.0	2.0
6	180	22.0	2.0
9	150	34.0	2.0
12	100	46.0	2.0
15	100	58.0	2.0
18	100	70.0	2.0

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$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	CIN	VIN	Cap.	Spec.	Part Name	Manufacturer
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 12.5V	10µF	25V	GRM31CR71E106K	muRata
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 12.5V	10µF	25V	CM316X5R106K25ABH	Kyocera
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		all	10µF	50V	UMK325BJ106MM-T	Taiyo Yuden
Court         Vour         Cap.         Spec.         Part Name         Manufacture           ≤ 8V         47 $\mu$ F         16V         GRM32EB31C476KE15         muRata           ≤ 5V         22 $\mu$ F         10V         GRM31CR71A226M         muRata           ≤ 12.5V         10 $\mu$ F         25V         GRM31CR71A226M         muRata           ≤ 12.5V         10 $\mu$ F         25V         GRM31CR71E106K         muRata           ≤ 12.5V         22 $\mu$ F         16V         CM316X5R226K16AB         Kyocera           ≤ 12.5V         22 $\mu$ F         25V         CM32X5R226M25AB         Kyocera           ≤ 12.5V         10 $\mu$ F         25V         CM316X5R106K25ABH         Kyocera           ≤ 12.5V         10 $\mu$ F         25V         CM316X5R106K25ABH         Kyocera           all         10 $\mu$ F         50V         UMK325BJ106MM-T         Taiyo Yuden           CBST         Vour         Cap.         Spec.         Part Name         Manufacture           all         0.47 $\mu$ F         16V         EMK212BJ474KD-T         Taiyo Yuden           all         0.47 $\mu$ F         16V         C1608JB1C474K         TDK           D         VIN         Spec.         Part Name         <		•	•		·	
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Соит	Vout	Cap.	Spec.	Part Name	Manufacturer
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 8V	47μF	16V	GRM32EB31C476KE15	muRata
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 5V	22µF	10V	GRM31CR71A226M	muRata
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 12.5V	10µF	25V	GRM31CR71E106K	muRata
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 8V	22µF	16V	CM316X5R226K16AB	Kyocera
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 12.5V	22µF	25V	CM32X5R226M25AB	Kyocera
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		≤ 12.5V	10μF	25V	CM316X5R106K25ABH	Kyocera
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		all	10μF	50V	UMK325BJ106MM-T	Taiyo Yuden
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$					•	
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	CBST	Vout	Cap.	Spec.	Part Name	Manufacturer
all         0.47μF         16V         C1608JB1C474K         TDK           D         V <sub>IN</sub> Spec.         Part Name         Manufacture           ≤ 15V         15V 2A         SBS010M         SANYO           ≤ 15V         15V 2A         SS20015M         SANYO           all         40V 3A         CMS16         TOSHIBA           L         Ind.         Spec.         Part Name         Manufacture           2.2μH         5.4A         RLF7030T-2R2M5R4         TDK           4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yude           4.7μH         2.6A         NR6028T4R7M         Taiyo Yude		all	0.47μF	16V	EMK212BJ474KD-T	Taiyo Yuden
DV <sub>IN</sub> Spec.Part NameManufacture≤ 15V15V 2ASBS010MSANYO≤ 15V15V 2ASS20015MSANYOall40V 3ACMS16TOSHIBALInd.Spec.Part NameManufacture2.2µH5.4ARLF7030T-2R2M5R4TDK4.7µH3.4ARLF7030T-4R7M3R4TDK10µH2.5ASLF10145T-100M2R5TDK2.2µH2.7ANR6020T2R2NTaiyo Yude4.7µH2.6ANR6028T4R7MTaiyo Yude10µH2.5ANR6045T100MTaiyo Yude		all	0.47μF	16V	C1608JB1C474K	TDK
DV <sub>IN</sub> Spec.Part NameManufacture≤ 15V15V 2ASBS010MSANYO≤ 15V15V 2ASS20015MSANYOall40V 3ACMS16TOSHIBALInd.Spec.Part NameManufacture2.2µH5.4ARLF7030T-2R2M5R4TDK4.7µH3.4ARLF7030T-4R7M3R4TDK10µH2.5ASLF10145T-100M2R5TDK2.2µH2.7ANR6020T2R2NTaiyo Yuder4.7µH2.6ANR6028T4R7MTaiyo Yuder10µH2.5ANR6045T100MTaiyo Yuder			-			
≤ 15V         15V 2A         SBS010M         SANYO           ≤ 15V         15V 2A         SS20015M         SANYO           all         40V 3A         CMS16         TOSHIBA           L         Ind.         Spec.         Part Name         Manufacture           2.2µH         5.4A         RLF7030T-2R2M5R4         TDK           4.7µH         3.4A         RLF7030T-4R7M3R4         TDK           10µH         2.5A         SLF10145T-100M2R5         TDK           2.2µH         2.7A         NR6020T2R2N         Taiyo Yudei           4.7µH         2.6A         NR6028T4R7M         Taiyo Yudei           10µH         2.5A         NR6045T100M         Taiyo Yudei	D	Vin	Sp	ec.	Part Name	Manufacturer
≤ 15V         15V 2A         SS20015M         SANYO           all         40V 3A         CMS16         TOSHIBA           L         Ind.         Spec.         Part Name         Manufacture           2.2µH         5.4A         RLF7030T-2R2M5R4         TDK           4.7µH         3.4A         RLF7030T-4R7M3R4         TDK           10µH         2.5A         SLF10145T-100M2R5         TDK           2.2µH         2.7A         NR6020T2R2N         Taiyo Yudet           4.7µH         2.6A         NR6028T4R7M         Taiyo Yudet           10µH         2.5A         NR6045T100M         Taiyo Yudet		≤ 15V	15V	2A	SBS010M	SANYO
all         40V 3A         CMS16         TOSHIBA           L         Ind.         Spec.         Part Name         Manufacture           2.2μH         5.4A         RLF7030T-2R2M5R4         TDK           4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yudet           4.7μH         2.6A         NR6028T4R7M         Taiyo Yudet           10μH         2.5A         NR6045T100M         Taiyo Yudet		≤ 15V	15V	′ 2A	SS20015M	SANYO
L         Ind.         Spec.         Part Name         Manufacture           2.2μH         5.4A         RLF7030T-2R2M5R4         TDK           4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder		all	40V	′ 3A	CMS16	TOSHIBA
L         Ind.         Spec.         Part Name         Manufacture           2.2μH         5.4A         RLF7030T-2R2M5R4         TDK           4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder						
2.2μH         5.4A         RLF7030T-2R2M5R4         TDK           4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder	L	Ind.	Sp	ec.	Part Name	Manufacturer
4.7μH         3.4A         RLF7030T-4R7M3R4         TDK           10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder		2.2μH	5.4	4A	RLF7030T-2R2M5R4	TDK
10μH         2.5A         SLF10145T-100M2R5         TDK           2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder		4.7μH	3.4	4A	RLF7030T-4R7M3R4	TDK
2.2μH         2.7A         NR6020T2R2N         Taiyo Yuder           4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder		10µH	2.5	5A	SLF10145T-100M2R5	TDK
4.7μH         2.6A         NR6028T4R7M         Taiyo Yuder           10μH         2.5A         NR6045T100M         Taiyo Yuder		2.2μH	2.7	7A	NR6020T2R2N	Taiyo Yuden
10H 2.5A NR6045T100M Taivo Yuda		4.7μH	2.6	6A	NR6028T4R7M	Taiyo Yuden
		10µH	2.5	5A	NR6045T100M	Taiyo Yuden

### Table2 R1243 Recommended external components

### Soft Start Time Adjustment Function

The soft start time ( $t_{SS}$ ) of the R1243x Series is adjustable by adding the soft start time adjusting capacitor ( $C_{SS}$ ) to the TSS pin. The soft start time can be set longer than the internal soft start time (Typ.0.4ms).

For example, if the soft start time adjusting capacitor ( $C_{SS}$ ) is  $0.1\mu$ F, the externally adjusted soft start time will be 12ms (Typ.). If there is no need of adjusting the soft start time, leave TSS pin as open so that the internal soft start time (Typ.0.4ms) will be applied.



### **FLAG** Function

The R1243 Series has the flag output function by using the Nch open drain. If any abnormal condition is detected, the IC turns the Nch transistor on and turns the FLG pin low. If the condition returns to normal, the IC turns the Nch transistor off and turns the FLG pin high after the flag off delay time (Typ.0.25ms).

The followings are the abnormal conditions the IC can detect.

```
·CE="L" (Shut down) ·UVLO (Released voltage Typ.4.0V) ·Thermal Shutdown
·V<sub>FB</sub> Over Voltage Detection (Typ.0.6V) ·V<sub>FB</sub> Under Voltage Detection (Typ.0.4V)
·Active Latch function (Ver.A/C)
·Tss pin's Over Voltage Protection after the completion of soft start (Typ.3V)
```

The flag resistors ( $R_{FLG}$ ) have to be between  $10k\Omega$  to  $100k\Omega$ . If the flag function is not used, FLG pin has to be left open or connected to GND.



Fig.2 FLAG function sequence

### **Operation of The Buck Converter and The Output Current**

The DC/DC converter charges energy in the inductor when switch is ON, and discharges the energy from the inductor when switch is OFF and controls with less energy loss, so that a lower output voltage than the input voltage is obtained. The operation will be explained with reference to the following diagrams:



- Step 1: Switch turns on and current IL (=i1) flows, and energy is charged into Cout. At this moment, IL increases from ILmin (=0) to reach ILmax in proportion to the on-time period (ton) of Switch.
- Step 2: When Switch turns off, a rectifier Diode turns on in order that L maintains IL at ILmax, and current IL (=i2) flows.
- Step 3: IL (=i2) decreases gradually and reaches IL=ILmin=0 after a time period of topen, and Diode turns off. Provided that in the continuous mode, next cycle starts before IL becomes to 0 because toff time is not enough. In this case, IL value increases from this ILmin (>0).

In the case of PWM control system, the output voltage is maintained by controlling the on-time period (ton), with the oscillator frequency (fosc) being maintained constant.

### **Output Current and Selection of External Components**

The relation between the output current and external components is as follows:

When Switch of Lx is ON:

(Wherein, Ripple Current P-P value is described as  $I_{RP}$ , ON resistance of Switch and Diode of Lx are respectively described as  $R_{ONH}$  and  $V_F$  and the DC resistor of the inductor is described as  $R_{L}$ .)

When Switch is "OFF"(Diode is "ON") as toff:

Put Equation 2 to Equation 1 and solve for ON duty of Switch, ton / (toff + ton) = DON,

Don = (Vout + VF + RL × Iout) / (VIN + VF - RONH × IOUT)...... Equation 3

Ripple Current is as follows:

IRP = (VIN - VOUT - RONH × IOUT - RL × IOUT) × DON / fosc / L ..... Equation 4

The peak current (ILmax) passing through the inductor and the switch is obtained by the following equation.

ILmax = Iout + IRP / 2..... Equation 5

The valley Current (ILmin) is obtained by the following equation.

ILmin = Iout - IRP / 2 ..... Equation 6

If the valley current is smaller than 0 (ILmin<0), the step-down DC/DC converter enters the discontinuous current mode.

The current condition for the discontinuous current mode is as follows.

lout < IRP / 2 ...... Equation 7

It is important to note the peak current (ILmax) and the valley current (ILmin) when making the input/output conditions or selecting the external components.

\*The above explanation is based on the ideal operation of the continuous mode.

### **TYPICAL CHARACTERISTICS**

1) FB Voltage vs Temperature

### R1243x001x



### 3) Oscillator Frequency vs Temperature

### R1243x001A/R1243x001B



### 5) Maxduty vs Temperature

R1243x001A/R1243x001B



### 2) Driver On Resistance vs Temperature



### 4) Oscillator Frequency vs Temperature

R1243x001C/R1243x001D



6) Maxduty vs Temperature

# $(V_{IN}=12V)$ 95 90 90 90 85 80 75 -50 -25 0 25 50 75 100 Ta (°C)

### R1243x001C/R1243x001D

### 7) Foldback Frequency vs Temperature



### 9) Soft Start Waveform

R1243x001x tss=0.4ms



### 10) Efficiency vs Load Current



### 8) Foldback Frequency vs Temperature



R1243x001x

 $t_{ss}=12ms$ (R1243S001A, VIN=12V, VOUT=3.3V, Css=0.1µF, VFLGIN=5.0V, ROUT=3.3Ω(IOUT=1.0A), Ta=25°C) VCE (5V/DIV) VOUT (1V/DIV) VFLG (5V/DIV) (4ms/DIV)





### 11) Load Regulation



R1243x001A/B







0.816



(Ta=25°C)





Vout=18V



R1243x001C/D





12) Line Regulation



### R1243x001A/B **V**out=5.0V





R1243x001A/B



### R1243x001A/B





### R1243x001C/D



Vour=3.3V 3.36 3.34 3.32 3.30 3.32 3.30 3.28 3.26 3.24 3.6 9 12 15 18 21 24 27 30 Vin (V)

R1243x001C/D

R1243x001C/D



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